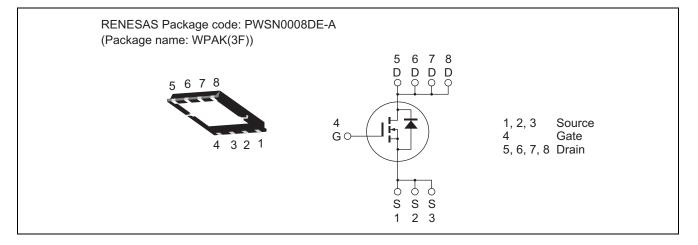


150V - 25A - MOS FET High Speed Power Switching Datasheet

Features

- Very low on-resistance
- $R_{DS(on)} = 0.038 \ \Omega$ typ. (at $I_D = 12.5 \ A$, $V_{GS} = 10 \ V$, $Ta = 25 \ ^{\circ}C$)
- Low gate charge
 - Qg = 37 nC typ. (at $V_{DD} = 120 \text{ V}$, $V_{GS} = 10 \text{ V}$, $I_D = 25 \text{ A}$, Ta = 25 °C)
- Low leakage current
- High speed switching

Outline



Absolute Maximum Ratings

| | | | $(Ta = 25^{\circ}C)$ |
|---|----------------------------------|-------------|----------------------|
| Item | Symbol | Ratings | Unit |
| Drain to source voltage | V _{DSS} | 150 | V |
| Gate to source voltage | V _{GSS} | ±30 | V |
| Drain current | I _D ^{Note4} | 25 | А |
| Drain peak current | I _{D (pulse)} Note1 | 50 | А |
| Body-drain diode reverse drain current | I _{DR} | 25 | А |
| Body-drain diode reverse drain peak current | I _{DR (pulse)} Note1 | 50 | А |
| Avalanche current | I _{AP} ^{Note2} | 22 | А |
| Avalanche energy | E _{AR} ^{Note2} | 36.3 | mJ |
| Channel dissipation | Pch ^{Note3} | 65 | W |
| Channel to case thermal impedance | θch-c | 1.93 | °C/W |
| Channel temperature | Tch | 150 | °C |
| Storage temperature | Tstg | -55 to +150 | °C |

Notes: 1. $PW \leq 10~\mu s,\,duty~cycle \leq 1\%$

- 2. STch = 25° C, Tch $\leq 150^{\circ}$ C
- 3. Value at Tc = 25°C
- 4. Limited by maximum safe operation area



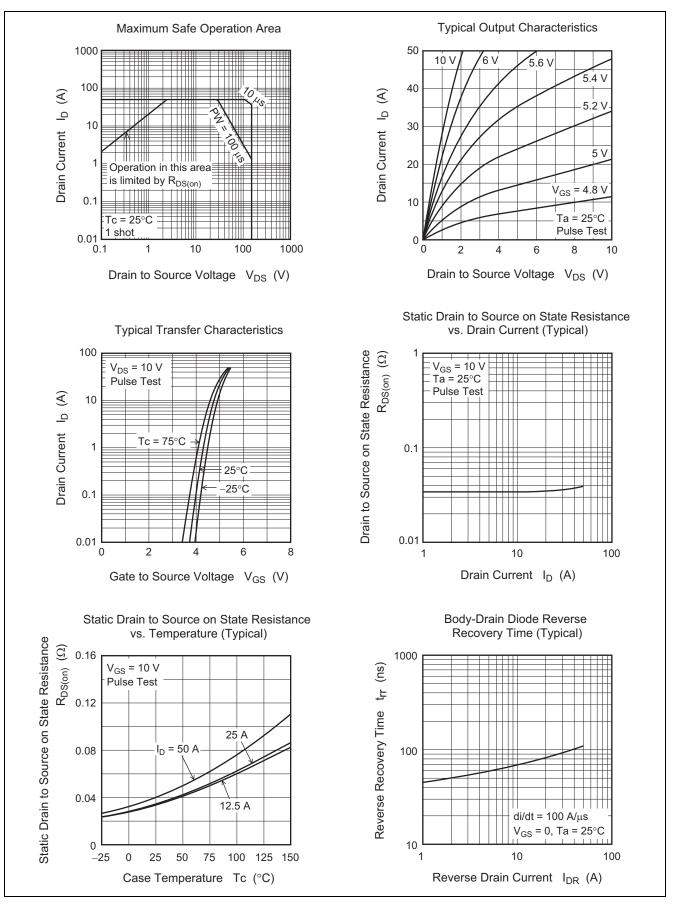
Electrical Characteristics

| | | | | | | $(Ta = 25^{\circ}C)$ |
|--|----------------------|-----|-------|-------|------|--|
| Item | Symbol | Min | Тур | Max | Unit | Test conditions |
| Drain to source breakdown voltage | V _{(BR)DSS} | 150 | | — | V | $I_D = 10 \text{ mA}, V_{GS} = 0$ |
| Zero gate voltage drain current | I _{DSS} | | | 1 | μΑ | $V_{DS} = 150 \text{ V}, \text{ V}_{GS} = 0$ |
| Gate to source leak current | I _{GSS} | _ | _ | ±1 | μΑ | $V_{GS}=\pm 30~V,~V_{DS}=0$ |
| Gate to source cutoff voltage | V _{GS(off)} | 2.5 | _ | 4.5 | V | $V_{DS} = 10 \text{ V}, I_D = 1 \text{ mA}$ |
| Static drain to source on state | R _{DS(on)} | _ | 0.038 | 0.048 | Ω | $I_D = 12.5 \text{ A}, V_{GS} = 10 \text{ V}^{\text{Note5}}$ |
| resistance | | | | | | |
| Input capacitance | Ciss | _ | 2200 | _ | pF | V _{DS} = 25 V |
| Output capacitance | Coss | | 240 | — | pF | V _{GS} = 0 f = 1 MHz |
| Reverse transfer capacitance | Crss | | 89 | — | pF | |
| Turn-on delay time | t _{d(on)} | _ | 22 | — | ns | $I_D = 12.5 \text{ A}$ $V_{GS} = 10 \text{ V}$ $R_L = 6 \Omega$ $Rg = 10 \Omega$ |
| Rise time | tr | _ | 33 | — | ns | |
| Turn-off delay time | t _{d(off)} | _ | 47 | — | ns | |
| Fall time | t _f | _ | 31 | — | ns | |
| Total gate charge | Qg | _ | 37 | — | nC | $V_{DD} = 120 V$ $V_{GS} = 10 V$ $I_D = 25 A$ |
| Gate to source charge | Qgs | _ | 12 | — | nC | |
| Gate to drain charge | Qgd | _ | 13 | — | nC | |
| Body-drain diode forward voltage | V _{DF} | | 0.81 | 1.45 | V | $I_F = 25 \text{ A}, V_{GS} = 0^{Note5}$ |
| Body-drain diode reverse recovery time | t _{rr} | | 88 | — | ns | $I_F = 25 \text{ A}, V_{GS} = 0$ |
| | | | | | | di _F /dt = 100 A/µs |

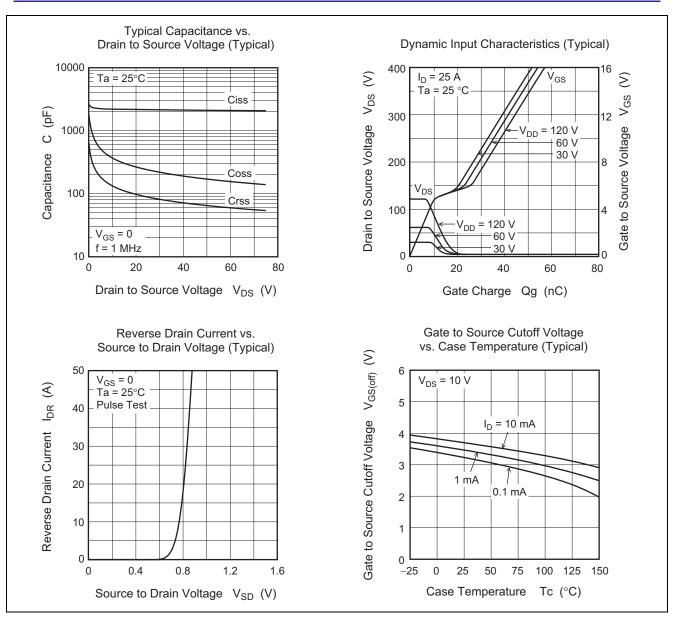
Notes: 5. Pulse test



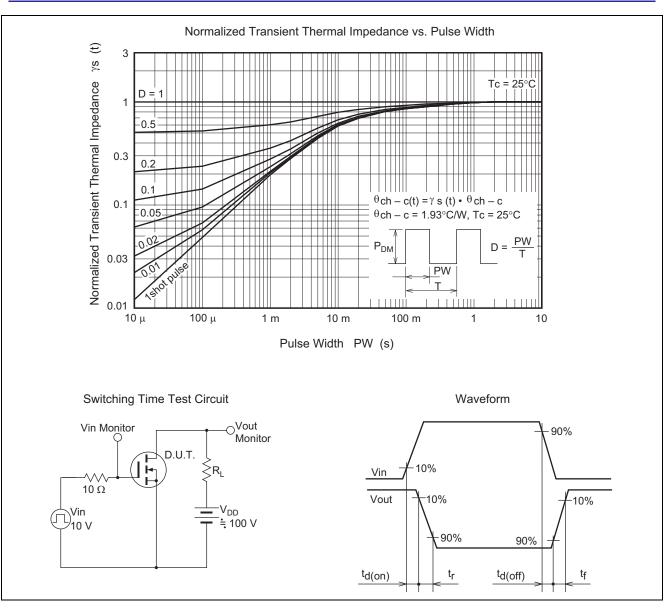
Main Characteristics





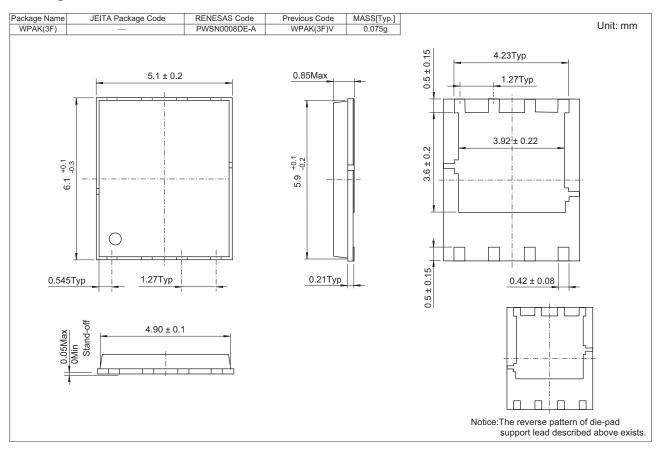








Package Dimensions



Ordering Information

| Orderable Part Number | Quantity | Shipping Container |
|-----------------------|----------|--------------------|
| RJK1575DPA-00#J5A | 3000 pcs | Taping |



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Renesas Electronics America Inc.

2880 Scott Boulevard Santa Ciara, CA 95050-2554, U.S.A.

Tel: +1-408-588-6000, Fast: +1-408-588-6130

Renesas Electronics Canada Limited

1011 Nicholson Road, Newmarket, Ontario L3Y 9C3, Canada

Tel: +1-905-988-5441, Fast: +1-905-988-3220

Renesas Electronics Europe Limited

Dukes Meadow, Millboard Road, Bourne End, Buckinghamshire, SL8 5FH, U.K

Tel: +44-1628-651-700, Fax: +444-1628-651-804

Renesas Electronics Europe GmbH

Arcadiastrasse 10, 40472 Disseldorf, Germany

Tel: +49-211-65030, Fax: +449-211-6503-1327

Renesas Electronics (Shanghal) Co., Ltd.

7th Floor, Quantum Plaza, No.27 ZhiChunLu Haidian District, Beijing 100083, P.R.China

Tel: +86-10-8235-1155, Fax: +862-10-8235-7679

Renesas Electronics (Shanghal) Co., Ltd.

Unit 204, 205, AZIA Center, No. 1233 Lujiazui Bing Rd., Pudong District, Shanghai 200120, China

Tel: +862-78587/7588

Renesas Electronics Hong Kong Limited

Unit 1601-1613, 16FL, Tower 2, Grand Century Place, 193 Prince Edward Road West, Mongkok, Kowloon, Hong Kong

Tel: +862-28175-9600, Fax: +862 2886-9022/9044

Renesas Electronics Taiwan Co., Ltd.

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Tel: +652-785930, Fax: +852 2886-9022/9044

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